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Abstract. The versatility of hot embossing for shaping photonic components on-chip for mid-infrared (IR) integrated optics, using a hard mold, is demonstrated. Hot embossing via fiber-on-glass (FOG), thermally evaporated films, and radio frequency (RF)-sputtered films on glass are described. Mixed approaches of combined plasma etching and hot embossing increase the versatility still further for engineering optical circuits on a single platform. Application of these methodologies for fabricating molecular-sensing devices on-chip is discussed with a view to biomedical sensing. Future prospects for using photonic integration for the new field of mid-IR molecular sensing are appraised. Also, common methods of measuring waveguide optical loss are critically compared, regarding their susceptibility to artifacts which tend artificially to depress, or enhance, the waveguide optical loss.

Keywords: mid-infrared; integrated optics; laser physics; optical materials.

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1 Introduction

The mid-infrared (IR) part of the electromagnetic spectrum spans 3- to 25-μm wavelength and encompasses the fundamental vibrational absorption signatures of molecular species.1 Small footprint biomedical, and chemical, mid-IR sensors, based on evanescent field sensing of molecular species, are attractive for low-cost, widely accessible, health, environmental, and security monitoring. This demands miniaturization and integration of mid-IR photonic components. Mid-IR evanescent field sensing requires no fluorescent tag nor labeling of the analyte. The sensing is not inferred indirectly, for instance from a changed refractive index. Rather the sensing is direct and directly gives the molecular identity of the analyte.

Chalcogenide glasses are attractive materials from which to fabricate mid-IR photonic sensing devices. Chalcogenide glasses exhibit an optical transmission window within the range of ∼500 nm to ∼25-μm wavelength; high linear (∼2 to ∼3.5) and nonlinear refractive indices; sufficient mechanical, and chemical, robustness, and low optical loss. Ultralow optical loss (down to 12 dB km−1) has been demonstrated for chalcogenide glass optical fibers based on simple compositions (such as As-S) by the Group of Churbanov.2 Although waveguides usually exhibit higher loss than the analogous optical fibers (whatever the glass type), this very low fiber loss bodes well for low loss photonic integrated circuitry based on chalcogenide glasses.

Chalcogenide glasses are not only suitable as passive waveguide conduits for the mid-IR but also as active evanescent field mid-IR sensors3,4 and as small, bright mid-IR sources on-chip.5,6

Chalcogenide planar waveguides are usually fabricated in a two-step process: first making a thin chalcogenide glass film and then patterning that film. Chalcogenide planar waveguides have been fabricated by means of pulsed laser deposition of thin films7 followed by e-beam writing8 or photorefraction9 to shape planar waveguides; thermal evaporation of thin films followed by traditional lithography using wet and/or dry etching10,11 or a soft-imprinting stamp12 or ion-implantation12 or laser-beam writing12,13 or complementary metal-oxide-semiconductor (CMOS)—compatible patterning14 including reflow15 to create the planar waveguide; or solution deposition of thin films followed by a soft-imprinting stamp16 to shape the waveguides.

There has been some progress toward volumetric photonic integration, i.e., beyond two-dimensional planar waveguides and toward making three-dimensional (3-D) waveguides. Thus, Coulombier et al.17 have demonstrated burying a fiber in bulk glass. Also, high intensity fs laser
3-D writing at 1.55-μm wavelength has been used to make waveguides by means of effecting photorefraction in the volume of a bulk glass; the photorefraction relies on the innately very high optical nonlinearities of chalcogenide glasses.\textsuperscript{9,10} We have been developing hot embossing of chalcogenide waveguides using a hard mold. This is made possible because chalcogenide glasses are readily shaped and patterned above their glass transition (\(T_g\)) and, on cooling below \(T_g\), the shaping and patterning are frozen-in. In this way, passive monomode rib waveguides of high numerical aperture (NA) have been demonstrated using hot embossing by hard mold with a variety of approaches\textsuperscript{19-23} via fiber-on-glass (FOG), thermally evaporated films, and radio frequency (RF)-sputtered films, on glass. Mixed approaches of combined plasma etching and hot embossing increase the versatility still further for engineering optical circuits on a single platform. This paper will review the latter body of work (for the detailed methodology see the original references \textsuperscript{19-24}) draw overarching conclusions and demonstrate how it is helping to pave the way for miniaturization of photonic chip devices for rapid and inexpensive scale-up of manufacture.

These hot embossed chalcogenide glass planar waveguides are not optically over-clad. Thus, because the chalcogenide glasses are invariably of higher refractive index (ranging \(\sim 2\) to \(3.5\)) than most molecular analytes, mid-IR light guided in an exposed waveguide core undergoes evanescent interaction with an abutted molecular analyte. The molecular analyte in contact with the glass waveguide core could be gaseous, or a static or flowing liquid within microfluidics to maintain the liquid, or a solid analyte, in optical contact with the waveguide. Mid-IR light guided in the waveguide core thereby suffers loss due to the fundamental vibrational absorption of the molecular species abutted to the core. So, light exiting the waveguide not only is coded with the molecular signature of the analyte but also the light absorption is proportional to the relative concentrations of the absorbing species. Thus quantitative sensing is likely achievable. Moreover, the integration of chalcogenide-glass shaped photonic circuitry on a GaAs platform for mid-IR operation, analogous to current silica-on-silicon photonic integration operating in the near-IR, opens up the prospect of optoelectronic integration on-chip for mid-IR sensing and imaging.

Application of hot embossing waveguides for fabricating molecular-sensing devices on-chip is discussed with a view to biomedical sensing. Future prospects for using photonic integration for the new field of mid-IR molecular sensing are appraised. Also, common methods of measuring waveguide optical-loss are critically compared, particularly with regard to their susceptibility to artifacts of the measurement approach which may tend artificially to depress, or enhance, the waveguide optical loss.

2 Hot Embossing

2.1 Processing

Toward fabricating mid-IR photonic integrated circuitry, we have developed a hot embossing processing (also known as thermal nanoimprinting), against a hard mold, to make rib waveguides, which is potentially fast, cheap, and up-scalable.\textsuperscript{19,23} Hot embossing of chalcogenide glass is conceptually straightforward [Fig. 1(a)]. Usually, flat glass is heated \textit{in vacuo} to above its glass transition (\(T_g\)) and then pressed against a mold isothermally, for a certain time at temperature, and under a prescribed load. The load is removed while the mold is left in place during cooling of the pressed glass to its \(T_g\), followed by annealing. After annealing, cooling to ambient temperature and mold-removal, the mold imprint is retained in the glass surface. The finished glass sample exhibits accurate replication of the mold pattern in relief and the replication tolerance is ultimately limited by the quality of the surface finish of the mold.

2.2 Patterning Fidelity

Using a hard, silicon mold, the mold-fidelity of the patterning of hot-embossed chalcogenide glasses has been demonstrated to date to be at \(ca. \pm 30\) nm\textsuperscript{19,20} [Fig. 1(b)], but there is no reason why this cannot be improved. Surface roughness ultimately contributes to scattering loss in the waveguide and will affect the quality of the waveguide evanescent field interaction with the abutted analyte. A surface quality of \(ca. \pm 5\) nm surface roughness for Si waveguides is achievable\textsuperscript{25} for use at telecommunication wavelengths. Bearing in mind that the most useful part of the mid-IR spectrum for detection of molecular species is \(\sim 3-12\)-μm wavelength,\textsuperscript{1} then for mid-IR on-chip biosensors a larger surface
roughness can be tolerated. Furthermore, the ultimate surface roughness depends primarily on the mold quality and as patterned silicon molds are useful here (oxidation at the silicon mold surface to silica renders it nonstick to chalcogenide glasses), there is potential for very low surface roughness after patterning.

3 Hot Embossing: Chalcogenide-on-Chalcogenide

For evanescent-field-mediated sensing, the top surface of the waveguide should be engineered to an exposed waveguide core and hence air-clad so as subsequently to allow the analyte to be in close core contact during the sensing. For the hot embossing process, we have mainly used a lower refractive index bulk chalcogenide glass to function as both the substrate and optical under-cladding. The developed core/clad pair of chalcogenide glasses are sufficiently matched in thermal properties (thermal expansion coefficient, viscosity/temperature relation) to allow thermal coprocessing. The closer in refractive index, the more likely it is that the core/cladding glasses will be amenable to thermal coprocessing because their chemical composition and molecular structure will be closer also. To test the approach, we rather selected a disparate refractive index pair exhibiting a high NA: with an As-Se core and Ge-As-Se acting as the under-cladding and substrate,19–24 (see Table 1); this pair has been used exclusively through our work in Refs. 19–23 and that has permitted us to compare more rigorously our hot embossing as the processing is modified. Table 1 highlights the key thermal properties when coprocessing two glasses using hot embossing with a hard mold. Here, As-Se core glass and Ge-As-Se under-cladding glass were selected to make high NA waveguides (Secs. 3.1–3.4) and Refs. 19–23. The key properties to control are: (i) avoidance of thermal expansion coefficient mismatch and (ii) Tg of the under-cladding substrate > Tg core glass—this gives the possibility of selectively (de)forming the core glass but not the under-cladding substrate because the under-cladding substrate is more viscous at any temperature T whereby: Tg ≤ T ≤ Tliq (Tliq is the liquidus). Thus molding of the thermally deposited supercooled thin film above Tg took place within a range of temperatures for which the substrate was at higher viscosity than the thin film.22 Tg of the Ge-As-Se glass substrate was 236° C, which is higher than that of bulk As-Se glass 178° C (Ref. 21) (Table 1). Throughout the work, the Ge-As-Se substrates have been obtained by glass melting and then ground, polished, and finally pressed flat under a vacuum before use.20–24

The refractive index difference of the core/under-clad pair has been sufficient to provide designs that were robust against the small process-induced uncertainty in actual refractive index. The NA was found to remain similar at longer wavelengths 22, which makes this pair suitable for forming high NA rib waveguides for both near- and mid-IR applications. Successful co-processing has been achieved using four different approaches: hot pressing fiber-on-glass (FOG); hot embossing of a thermally evaporated film (core glass) on glass, hot embossing of a radio frequency (RF) sputtered film on glass and also photolithography and dry etching, as follows in Secs. 3.1 to 3.4.

3.1 Fiber-on-Glass

For the FOG processing,21 chalcogenide-glass monomode rib waveguides were fabricated by means of hot pressing using a patterned hard silicon mold [Fig. 2(a)]. As-Se fibers were aligned such that each fiber lay in one channel in the mold with sufficient separation between fibers. The polished, flattened (by hot pressing) Ge-As-Se substrate was placed on top of the fibers in the mold and hot pressing was carried out. During the hot pressing, the fiber spread to fill the proximate mold channels and adhered to the Ge-As-Se substrate.

The one-step FOG approach produced waveguides comprised of over-clad/core/under-clad = air/As-Se/Ge-As-Se. Designed for monomode operation, one of the waveguides was an As-Se rib core of 5-μm width and 1.7-μm depth [Fig. 2(b)]. The lowest recorded optical loss of the monomode waveguides was 2.2 dB/cm at 1550-nm wavelength and the near-field image confirmed monomode guiding [Fig. 2(c)].21

3.2 Thermally Evaporated Film on Glass

The second method we have used was to evaporate thermally an As-Se chalcogenide glass film onto a Ge-As-Se chalcogenide glass substrate.23 Hot embossing of the thermally evaporated thin As-Se film was carried out using a silicon mold to make the waveguides. An example shown in Fig. 3 is of a monomode guiding rib core: 5.5-μm wide and 1.9-μm deep. The lowest recorded optical loss for the monomode waveguides was 2.9 dB/cm at 1550 nm. The refractive indices of the core and under-cladding at 1550 nm were 2.801 ± 0.01 and 2.590 ± 0.01, respectively.22 The waveguide exhibited excellent stability at ambient temperatures.

Advantages of thermal evaporation for depositing thin chalcogenide glass films include a relatively high deposition speed, but thermal evaporation can have difficulties in depositing materials with high melting points as well as multicomponent and/or composite materials with a large melting point difference between their constituents, where noncongruent evaporation usually occurs resulting in non-homogeneous films.23 Zakery and Elliot24 explain that the thermal-evaporation method is not suitable for the accurate transfer of stoichiometry of multicomponent glass films. The Group of Pradel28 has developed a thermal coevaporation approach using different targets to lay down simultaneously

| Table 1 | Highlights key thermal properties when coprocessing two glasses using hot embossing. Here, As-Se core glass and Ge-As-Se under-cladding glass were selected to make high NA waveguides (Secs. 3.1–3.4) and Refs. 19–23. The key properties to control are: (i) avoidance of thermal expansion coefficient mismatch and (ii) Tg of the under-cladding substrate > Tg core glass—this gives the possibility of selectively (de)forming the core glass but not the under-cladding substrate because the under-cladding substrate is more viscous at any temperature T whereby: Tg ≤ T ≤ Tliq (Tliq is the liquidus). Thus molding of the thermally deposited supercooled thin film above Tg took place within a range of temperatures for which the substrate was at higher viscosity than the thin film.22 Tg of the Ge-As-Se glass substrate was 236° C, which is higher than that of bulk As-Se glass 178° C (Ref. 21) (Table 1). Throughout the work, the Ge-As-Se substrates have been obtained by glass melting and then ground, polished, and finally pressed flat under a vacuum before use.20–24

<table>
<thead>
<tr>
<th>Glass composition</th>
<th>For high NA: refractive index difference (at 1.55-μm wavelength)</th>
<th>Difference in thermal expansion coefficient (°C⁻¹)</th>
</tr>
</thead>
<tbody>
<tr>
<td>As-Se, core</td>
<td>0.211</td>
<td>50</td>
</tr>
<tr>
<td>Ge-As-Se, underclad</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

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single components to obtain amorphous films with multicomponent compositions.

3.3 RF-Sputtered Films on Glass

A third method was to hot emboss rib waveguides in an As-Se film deposited using RF-magnetron sputtering on a Ge-As-Se glass substrate. Figure 4 shows an environmental scanning electron microscope (ESEM) image of the cleaved edge comprising an as-sputtered film of As-Se on a Ge-As-Se substrate. The nonvisible interface between the two chalcogenide compositions indicates a defect-free and well-adhered interface. The corresponding energy dispersive x-ray spectroscopy (EDX) line scan of the Ge, As, and Se elements across the interface allowed measurement of the sputtered film thickness, which was $4232 \pm 20$ nm.

It has been previously reported that, unlike thermal evaporation, RF-sputtering can be responsible for the formation of column-like structures in deposited films. These column-like structures were detected, using atomic force microscopy, by Balan et al. in thin films of some chalcogenide multicomponent systems that had been deposited on unheated silicon and glass substrates. The refractive index of these films was also shown to decrease with the film thickness because of a change in the morphology (porosity) of the films with thickness. This columnar structure was explained in terms of the influence of deposition conditions, and in particular, the ratio of substrate temperature to thin film melting point (K). Furthermore, Balan et al. showed that, in general, multicomponent chalcogenide sputtered films of $\sim 4$-μm depth exhibited clustered-columns of approximate diameter 250 nm [confirmed by scanning electron microscopic (SEM) images], leading to a porosity estimated at $\sim 33\%$ and a measured decrease in refractive index of $\sim 10\%$ compared to $<1$-μm depth films.

As can be seen from Fig. 4 here, there was no apparent columnar structure present in ESEM micrographs of the RF-sputtered films collected for this work. Waveguides 4- to 6-μm wide and 1.9 ± 0.1-μm high were fabricated using hot embossing against a hard Si mold [Figs. 5(a) and 5(b)] and waveguide optical loss was measured using the Fabry-Perot technique [Figs. 6(a) and 6(b)].
The Fabry-Perot method, which is known to overestimate loss [see Sec. 5, Fig. 6(a)], gave losses of $<0.78 \text{ dB cm}^{-1}$ for the transverse electric (TE) mode and $<0.81 \text{ dB cm}^{-1}$ for the transverse magnetic (TM) mode, at 1550-nm wavelength. Thus the waveguide loss was lower compared to both hot embossing with FOG (Sec. 3.1) and hot embossing a thermally evaporated As-Se glass thin film on a Ge-As-Se glass substrate (Sec. 3.2) (Table 2).

### 3.4 Mixed Approaches of Combined Plasma Etching and Hot Embossing

Following the work done by Choi et al.\textsuperscript{31} on etching thermally evaporated As-S films in a CHF$_3$ (O$_2$ free) plasma, we have developed a similar inductively coupled plasma etching process.\textsuperscript{24} This was applied initially to etch rib structures in As-S bulk glass in order to repeat the Choi et al.\textsuperscript{31} results and standardize the procedures. After that, the dry etching process was applied to shape rib waveguides in As-Se thin films that had been either RF-sputtered onto silicate-glass microscope slides or RF-sputtered onto Ge-As-Se chalcogenide glass substrates.\textsuperscript{24} The lowest recorded
loss was for a 5.5-μm wide × 0.98-μm deep As-Se rib on Ge-As-Se glass substrate (see Fig. 7) and was 1.05 ± 0.02 dB cm⁻¹ for the quasi-TE mode and 1.12 ± 0.01 dB cm⁻¹ for the quasi-TM mode.

3.5 Summary

Table 2 summarizes the results in Secs. 3.1–3.4. From Table 2, optical loss results for the As-Se waveguides formed by dry etching of RF-sputtered films (ca. 1.0 dB cm⁻¹ at 1550 nm) were higher than the loss obtained for the same design of As-Se waveguides but which had been instead shaped by hot embossing against a hard silicon mold (cf. ca. 0.8 dB cm⁻¹ at 1550 nm). It is suggested that the extra loss found for the dry-etched As-Se waveguides compared to the hot embossed As-Se waveguides was associated with extra surface roughness.

A comparison of the pros and cons of hot embossed waveguides (fast, cheap, scalable, surface roughness dependent on integrity of mold and thus repeatable fabrication of successive waveguides with the same mold, but could not, for instance, be repeated on same chip due to the temperature cycling this would incur) versus plasma-etched waveguides (expensive, many-step processing, repeatable fabrication of successive waveguides once have optimized process, masking would allow revisiting same chip for further shaping) suggests that there are various advantages and disadvantages of both types of waveguide processing. Moreover, it is concluded that their use in combination, whereby hot embossed waveguides could be postprocessed using plasma etching, offers the greatest versatility of approach for mid-IR photonic integration.

4 Glass Stability, Environmental and Photostability of Embossed Waveguides

4.1 Glass Stability

4.1.1 General comments

The term glass stability refers to the ability of a glass to remain amorphous and not to devitrify (i.e., crystallize). This is important not only during waveguide manufacture but also in service. For chalcogenide glasses, so long as the operating temperature remains less than 50 K below $T_g$, then no reflow of the material is expected to occur at normal pressure.

However, at and above $T_g$ up to the liquidus, the material transforms to a supercooled liquid and, in thermodynamic terms, is therefore metastable with respect to the primary crystallizing phase. In the absence of heterogeneous nuclei, the kinetics of transformation from the supercooled liquid to the crystalline phase of chalcogenide glasses can be remarkably slow compared to, for example, the speed of this type of phase transformation of some of the metallic glasses and $\text{ZnF}_2 - \text{BaF}_2 - \text{LaF}_3 - \text{AlF}_3 - \text{NaF}$ glasses, but is still at least an order of magnitude faster than devitrification rates of common multicomponent silicate glasses. The situation is worsened in the presence of heterogeneous nuclei (foreign material) and this is why very pure glasses should be used; also, heating the chalcogenide glasses in the presence of

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Table 2

<table>
<thead>
<tr>
<th>Designed to be As-Se waveguide on Ge-As-Se substrate?</th>
<th>Glass-melted, ground, polished, pressed-flat Ge-As-Se substrate?</th>
<th>Method of As-Se deposition on Ge-As-Se substrate? (prior to shaping waveguide)</th>
<th>Method of shaping rib waveguide</th>
<th>Lowest recorded loss (using Fabry-Perot method) of rib waveguide at 1550-nm wavelength</th>
<th>Monomode in near-field?</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Y</td>
<td>Y</td>
<td>As-Se fiber (FOG) (Sec. 3.1)</td>
<td>Hot embossing (hot pressing fiber into silicon mold on top of the substrate)</td>
<td>2.2 dB cm⁻¹ for waveguides 5-μm wide × 1.7-μm deep</td>
<td>Y</td>
<td>21</td>
</tr>
<tr>
<td>Y</td>
<td>Y</td>
<td>Thermal evaporation (Sec. 3.2)</td>
<td>Hot embossing</td>
<td>2.9 dB cm⁻¹ for waveguides 5.5-μm wide × 1.9-μm deep</td>
<td>Y</td>
<td>22</td>
</tr>
<tr>
<td>Y</td>
<td>Y</td>
<td>RF-sputtering (Sec. 3.3)</td>
<td>Hot embossing</td>
<td>&lt;0.78 dB cm⁻¹ for TE mode, &lt;0.81 dB cm⁻¹ for TM mode, for waveguides 4- to 6-μm wide × 1.9 ± 0.1-μm deep</td>
<td>Y</td>
<td>23</td>
</tr>
<tr>
<td>Y</td>
<td>Y</td>
<td>RF-sputtering (Sec. 3.4)</td>
<td>Dry etch</td>
<td>1.05 ± 0.02 dB cm⁻¹ for quasi-TE mode, 1.12 ± 0.01 dB cm⁻¹ for quasi-TM for waveguide 5.5-μm wide 0.98-μm deep</td>
<td>Y</td>
<td>24</td>
</tr>
</tbody>
</table>

Fig. 7 SEM cross-sectional view of an As-Se rib waveguide 5.5-μm wide and 0.98-μm deep that had been shaped by dry etching of an RF-sputtered As-Se film on a Ge-As-Se substrate.²⁴
other materials should be attempted with caution. In addition, there have been reports of chalcogenide glasses devitrifying under the action of subbandgap light at ambient temperatures termed photocristallization.\textsuperscript{52} Despite the potential for devitrification, the chalcogenide glasses are more likely to be limited during manufacture and use by problems of volatilization, oxidation, and hydrolysis above $T_g$.

4.1.2 During manufacture

We have found excellent glass stability of the selenide-glass-based hot embossed waveguides during manufacture, use, and storage under ambient conditions. They remain amorphous according to x-ray diffractometry of the devices. Optical loss measurements have been demonstrated to remain constant for at least 3 weeks. This observed glass and rib-waveguide stability is in stark contrast to the results of some others for chalcogenide glass rib waveguides. Thus the group of Luther-Davies has reported postprocessing problems of crystallization of As-S rib waveguides which had been formed in thermally evaporated As-S films on a substrate of oxidized Si.\textsuperscript{33} In addition, Hu et al.\textsuperscript{34} reported that they coated thermally evaporated As-S with SU8 polymer to “prevent surface oxidation of devices in As-S.” Moreover, Hu et al.\textsuperscript{35} postheat-treated waveguides to “stabilize the glass structure.” Yet no such problems were reported when they applied similar processing to form Ge-Sb-S rib waveguides, in which, purposefully, no additional upper cladding layer was added.\textsuperscript{3} As an alternative explanation to crystallization by surface photooxidation of As$_{40}$S$_{60}$ rib waveguides, formed in thermally evaporated As$_{40}$S$_{60}$ films, Wang et al.\textsuperscript{35} have referred to a type of intrinsic phase separation in As$_{40}$S$_{60}$ to explain crystallization of pulsed laser deposited films of As$_{40}$S$_{60}$ and this intrinsic phase separation is suggested to be present even in As$_{40}$S$_{60}$ bulk glass itself, according to the ideas of Georgie et al., but these ideas are not universally accepted.

As eloquently reviewed by Nordman et al., what is generally accepted is that thermally evaporated As$_{40}$S$_{60}$ films inevitably contain molecular clusters, composed of both heteropolar bonds and homopolar “wrong” bonds, found in the vapor state itself, and that heat-treating can help to lower the prevalence of the “wrong bonds” and also densify thermally evaporated films to achieve more nearly the same refractive index as that of the parent bulk glass. From the above studies, it might be concluded that the thermal-evaporation process may be more problematic and that RF-sputtering might lead to more robust glass films. However, the observations of Balan et al.\textsuperscript{29} (see Sec. 3.3) that RF-sputtering can be responsible for the formation of column-like structures in thin chalcogenide glass films deposited on unheated silicon and glass substrates indicate that caution must be applied to both thermal evaporation and RF-sputtering methods of making chalcogenide films and film integrity cannot just be assumed.

4.2 Mechanical and Environmental (Including Photo-) Stability

The chalcogenide glasses exhibit low phonon energies and hence mid-IR transparency precisely because they are based on weaker chemical bonding than silicate glasses. Because of the weaker chemical bonding, inevitably the chalcogenide glasses have both lower fracture stress and modulus of rupture than silicate glasses.\textsuperscript{38} Corrosion resistance of chalcogenide glasses to water vapor and liquid water at ambient temperatures is good, but strong alka
des and acids should be avoided. No photoinduced changes under ambient lighting conditions have been observed to date in our waveguides. Also in preliminary experiments, the resistance of RF-sputtered chalcogenide films to photodamage was apparently good for exposures of several minutes to fiber-coupled lasers, viz. 7 mW HeNe cw (651-nm wavelength); 40 mW cw 974 nm and 1320 nm diode lasers,\textsuperscript{24} i.e., the waveguide optical loss at 1.55 μm was unaffected by these exposures. But photodarkening of chalcogenide glasses is known to occur, as reported by Tanaka.\textsuperscript{39}

5 Brief Comparison of Methods to Measure Waveguide Loss

Throughout the literature, there are several common methods to measure the optical loss of short optical waveguides. Each method has susceptibility to particular artifacts which tend artificially either to depress or to enhance loss.

The most accurate method is the cut-back approach. This is commonly used for measuring the optical loss of optical fibers, for which long pathlengths are available. The cut-back method involves measuring the output light intensity from the exit face of the waveguide ($I_{\text{out-1}}$), then keeping the same input conditions, the waveguide is “cut-back” (cleaved) to a shorter length(s) and the output intensity of light remeasured ($I_{\text{out-2}}$). Loss in dB cm$^{-1}$ is calculated from the ratio of the two output intensities and the length cut-back ($L$) (dB/cm = $-10 \log_{10}(I_{\text{out-1}}/I_{\text{out-2}}) L$).\textsuperscript{60} However, the shorter the waveguide, the more it is physically difficult to obtain a good cleave (whereby the cleave itself does not dominate the loss) and meaningful results. An alternative to this destructive cut-back approach is to fabricate waveguide sections of different length.

The Fabry-Perot approach [see Fig. 5(a)], adopted by our Group, is a fundamental approach. The cavity length is changed by raising the temperature of the waveguide above ambient (it expands), we do this simply by holding a soldering-iron close. Here, the measured optical loss results tend to be higher than the actual. This is because the Fabry-Perot technique is concerned with measuring the round-trip loss inside the cavity of the waveguide. Due to the nature of the cleaving process, defects are expected on the cleaved end-faces of the waveguide and so the end-face modal reflectivity will be lower than the numerical values. Hence, the loss values quoted are regarded as an upper limit to the actual waveguide loss.

The insertion loss can also be used as a measure of propagation loss. However, some assumptions must then be made about coupling losses and reflections, so giving rise to some uncertainty in the estimated loss.

6 Prospects for Hot Embossing for Mid-IR Chip Biosensors and Other Molecular Sensors

To date, there are limited reports of mid-IR (i.e., wavelength range 3 to 25 μm) integrated chip-sensors based on any waveguide material for evanescent field sensing. The chief reason holding back this technology is that such sensing cannot be fully exploited without readily available bright, discrete, and broadband mid-IR sources, of the appropriate
output (wavelength matched to the vibrational absorption of the analyte), preferably on-chip.

In the shorter wavelength, near-IR region (>7500 nm, <3 μm), evanescent field sensing has been demonstrated in an integrated chalcogenide glass slab waveguide.¹ The chalcogenide glass waveguide consisted of exposed core of a 400-nm thick Ge-Sb-Se film on top of the oxidized Si; the waveguide loss was reported as 2.3 dB cm⁻¹ at 1550 nm. These waveguides were successfully used in conjunction with microfluidics as a near-IR evanescent sensor to detect the [N-H] vibrational absorption of N-methylaniline at 1500 nm.

However, this near-IR N-H absorption is a weak overtone. Far stronger, fundamental vibrational absorption bands of [N-H] exist in the mid-IR beyond 3-μm wavelength for this molecule potentially giving better optical contrast of sensing and hence greater sensor sensitivity. So, mid-IR sensing is the way forward.

The first steps of biofunctionalization of a planar chalcogenide sulfide waveguides have been demonstrated¹ laying down a gold-coating on top of the waveguide, then the anchor molecules [1,1-mercaptoundecanoc acid (MUA)] were hooked on the gold to form SAMs (self-assembly monolayers) onto which antibodies could be attached.

But, such biofunctionalization of waveguides is unnecessary for waveguide sensing in the mid-IR because mid-IR molecular detection is direct.

A true mid-IR on-chip sensor has been demonstrated by Chang et al. comprising on-chip mid-IR evanescent field sensing of cocaine.²¹ The waveguide in this case was a germanium (Ge) strip waveguide on a silicon (Si) substrate integrated with a microfluidics to detect cocaine in tetra-chloroethylene solutions. In the evanescent field of the waveguide, cocaine exhibited characteristic vibrational absorption at 5.5 μm, and the quantum cascade laser (QCL) mid-IR source was matched to that wavelength. The QCL was off-chip.

Chalcogenide glass rib waveguides would be suitable for this application and could substitute the Ge waveguide for sensing a plethora of molecules. But the limitation is the availability of QCLs operating at the correct wavelength to match the characteristic molecular absorptions. To truly open up the field of mid-IR integrated evanescent field sensors, bright broadband mid-IR on-chip sources are now required and short supercontinuum source devices are attractive for this.²¹

7 Conclusions

This paper has demonstrated that low optical loss, mid-IR chalcogenide-glass waveguides can be readily fabricated via the hot-embossing technique; the processing is fast, scalable, and obviates the need for expensive equipment. On the other hand, conventional photolithography and dry etching are also successful in making chalcogenide glass integrated photonic circuitry. The two techniques combined together present a substantial versatile approach and a gateway to photonic integration on-chip. An open-core chalcogenide glass rib waveguide is a simple format to integrate with microfluidics. The microfluidic channel brings molecular liquids or solutions into close proximity with the waveguide for evanescent-field detection of the vibrational absorption of the abutted molecular analyte. Similarly molecular gases and solids can be brought into proximity of the waveguide for mid-IR evanescent-field detection.

What is now needed is new bright, mid-IR broadband sources on-chip. QCLs operating in the mid-IR can provide sufficient brightness for mid-IR evanescent field sensing; they are suitable as on-chip, discrete, bright mid-IR sources but limited in wavelength range. Short SCG waveguide or taper sources are exceedingly attractive as on-chip, broadband, bright mid-IR sources to enable detection of characteristic spectral absorptions across the mid-IR, to bring about unambiguous identification and quantification of molecular analytes.

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